



A Product Line of Diodes Incorporated

ZXT13N50DE6

50V NPN LOW SATURATION SWITCHING TRANSISTOR

Features

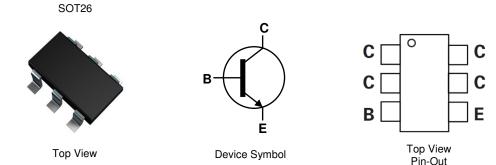
- BV_{CEO} > 50V
- I_C = 4A Continuous Collector Current
- I_{CM} = 10A Peak Pulse Current
- R_{CE(SAT)} = 36mΩ for a Low Equivalent On-Resistance
- Low Saturation Voltage (100mV max @ 1A)
- hFE Characterized up to 10A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208
- Weight: 0.015 grams (Approximate)

Applications

- DC–DC Converters
- Power Management Functions
- Power Switches
- Motor Control



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13N50DE6TA	AEC-Q101	N50D	7	8	3,000
ZXT13N50DE6TC	AEC-Q101	N50D	13	8	10,000
ZXT13N50DE6QTA	Automotive	N50D	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

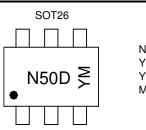
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally

the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



$$\begin{split} \text{N50D} &= \text{Product Type Marking Code} \\ \text{YM} &= \text{Date Code Marking} \\ \text{Y or } \overline{\text{Y}} &= \text{Year (ex: C = 2015)} \\ \text{M or } \overline{\text{M}} &= \text{Month (ex: 9 = September)} \end{split}$$

Date Code Key

Year	2015	2	016	2017	2018	2019	2020	2021	20	22	2023	2024	2025
Code	С		D	Е	F	G	Н			J	К	L	М
Montl	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	2	3	4	5	6	7	8	9	0	N	D





Absolute Maximum Ratings (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	100	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7.5	V
Base Current	I _B	500	mA
Continuous Collector Current	Ι _C	4	A
Peak Pulse Collector Current	I _{CM}	10	A

Thermal Characteristics (@T_A = +25 °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)		1.1 8.8	W	
Linear Derating Factor	(Note 7)	- P _D	1.7 13.6	mW/°C	
Thermal Desistance, Junction to Ambient	(Note 6)	P	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	73		
Thermal Resistance, Junction to Lead	(Note 8)	R _{θJL}	18.6		
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

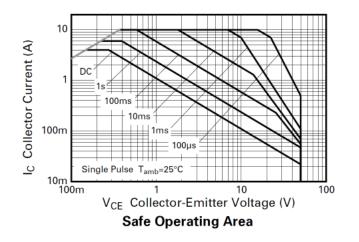
6. For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state. Notes:

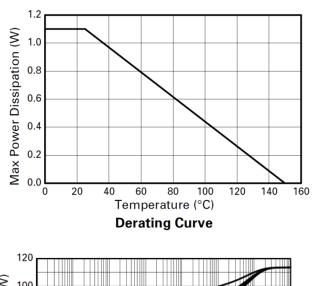
7. Same as Note 6, except the device is measured at t \leq 5 sec.

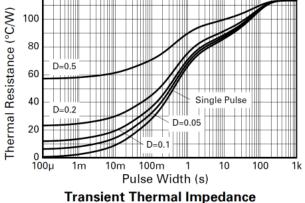
Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



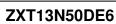
Thermal Characteristics and Derating Information









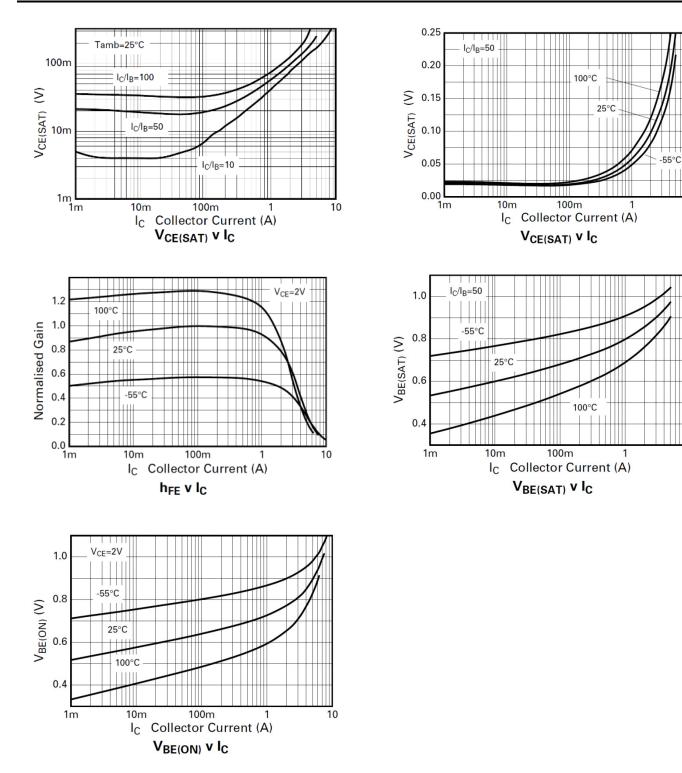


Electrical Characteristics (@T _A = +25 °C	, unless oth	erwise sp	pecified.)			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS					•	
Collector-Base Breakdown Voltage	BV _{CBO}	100	190	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	50	70	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7.5	8.5	_	V	I _E = 100μA
Collector-Base Cutoff Current	I _{CBO}	_	—	100	nA	V _{CB} = 80V
Emitter Cutoff Current	I _{EBO}	—	—	100	nA	$V_{EB} = 6V$
Collector-Emitter Cutoff Current	I _{CES}	—	—	100	nA	$V_{CES} = 80V$
ON CHARACTERISTICS (Note 10)						
		250	400	—		$I_C = 10mA, V_{CE} = 2V$
DC Current Gain	h _{FE}	300	450	900	—	$I_C = 1A, V_{CE} = 2V$
		100	220	_		$I_C = 4A, V_{CE} = 2V$
		10	30	_		$I_C = 10A, V_{CE} = 2V$
		—	8	12	mV	$I_{C} = 100 \text{mA}, I_{B} = 10 \text{mA}$
		—	75	100		$I_C = 1A$, $I_B = 10mA$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	150	200		$I_C = 3A, I_B = 50mA$
		—	175	230		$I_{\rm C} = 4$ A, $I_{\rm B} = 100$ mA
		—	145	180		$I_{\rm C} = 4A, I_{\rm B} = 400 {\rm mA}$
Base-Emitter Saturation Voltage	V _{BE(sat)}	—	—	1.0	V	$I_{\rm C} = 4$ A, $I_{\rm B} = 100$ mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	—	—	0.9	V	$I_C = 4A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T	_	115	—	MHz	$V_{CE}=10V,I_C=50mA,f=50MHz$
Output Capacitance	C _{obo}	—	31	—	pF	V _{CB} = 10V, f = 1MHz
Turn-On Time	t _(on)	—	220	_	ns	$V_{CC} = 10V, I_C = 1A$
Turn-Off Time	t _(off)	_	830	_	ns	$I_{B1} = I_{B2} = 20mA$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)



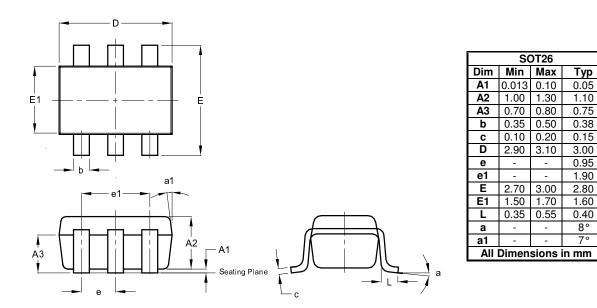
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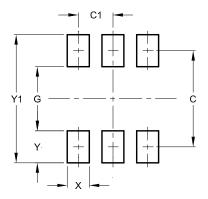
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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